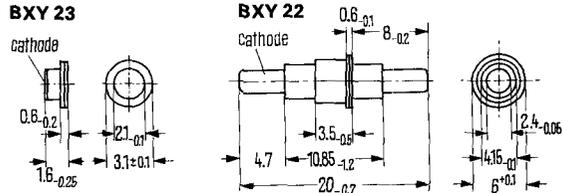


BXY 22 G, BXY 22 H, BXY 22 J, BXY 23

Depletion-layer varactor

Are capacitance diodes for tuning, switching and modulator applications up into the GHz range.

| Type | Order number |
|----------|----------------|
| BXY 22 G | Q 60223-Y 22-G |
| BXY 22 H | Q 60223-Y 22-H |
| BXY 22 J | Q 60223-Y 22-J |
| BXY 23 | Q 60223-Y 23 |



Weight approx. 0.1 g
Dimensions in mm

Weight approx. 1.4 g

| | BXY 22 G BXY 22 H BXY 22 J | BXY 23 | |
|--|----------------------------------|-------------------|--------------------|
| Maximum ratings ($T_{amb} = 25^\circ\text{C}$) | | | |
| Reverse voltage | V_R | 30 | V |
| Forward current | I_F | 200 | mA |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_s | -55 to +175 | $^\circ\text{C}$ |
| Power dissipation | P_{tot} | 1.2 | W |
| Thermal resistance | | | |
| between junction and case | $R_{thJcase}$ | ≤ 70 | K/W |
| between junction and static ambient air | R_{thJamb} | ≤ 150 | K/W |
| Static characteristics | | | |
| Reverse current | | | |
| ($V_R = 30\text{ V}$; $T_{amb} = 25^\circ\text{C}$) | I_R | ≤ 10 | nA |
| Reverse current | | | |
| ($V_R = 30\text{ V}$; $T_{amb} = 60^\circ\text{C}$) | I_R | ≤ 100 | nA |
| Forward voltage | | | |
| ($I_F = 200\text{ mA}$; $T_{amb} = 25^\circ\text{C}$) | V_F | ≤ 1 | V |
| Dynamic characteristics ($T_{amb} = 25^\circ\text{C}$) | | | |
| Case capacitance | C_{case} | 0.85 | pf |
| Case series inductance | L_s | 2 | nH |
| Temperature dependence of the diode ($V_R = 3\text{ V}$) | TK_{CD} | $4 \cdot 10^{-4}$ | $1/^\circ\text{C}$ |
| Capacitance ratio ($V_R = 3\text{ to }25\text{ V}$; $f = 1\text{ MHz}$) | C_{D3} | 2 to 2.5 | - |
| | C_{D25} | | |
| Voltage dependence of the junction capacitance ($V_R = 3\text{ to }25\text{ V}$) | n^1 | 2 to 2.3 | - |
| Series resistance ($V_R = 3\text{ V}$; $f = 2.4\text{ GHz}$) | R_s | < 1.5 | Ω |

| | BXY 22 G | BXY 22 H | BXY 22 J | BXY 23 | |
|---|------------------|-------------------|-----------------|-------------------|----|
| Diode capacitance | | | | | |
| ($V_R = 15\text{ V}$; $f = 1\text{ MHz}$) C_D^2 | 10 (8.8 to 11.2) | 12 (10.8 to 13.2) | 14.5 (13 to 16) | - | pf |
| ($V_R = 3\text{ V}$; $f = 1\text{ MHz}$) C_D^2 | - | - | - | 12 (10.7 to 13.3) | pf |

¹⁾ $C_j(V_{R1}) = \left(\frac{V_{R2} + V_D}{V_{R1} + V_D} \right) \frac{1}{n}$; $V_D \approx 0.7\text{ V}$

²⁾ $C_D = C_j + C_{case}$